NSN 5962-01-161-3535

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Body Length:	
1.290 inches	
Body Width:	
Between 0.500 inches	and 0.610 inches
Body Height:	
Between 0.150 inches	and 0.210 inches
Maximum Power Dise	sipation Rating:
1.02 watts	
Operating Tempuratu	ire Range:
-55.0/+125.0 degrees	celsius
Storage Tempurature	e Range:
-65.0/+150.0 degrees	celsius
End Application:	
Radar system, type an	/fps-117
Features Provided:	
Hermetically sealed ar	nd monolithic and bipolar and high impedance and schottky and programmable
Inclosure Material:	
Ceramic and glass	
Inclosure Configurat	ion:
Dual-in-line	
Output Logic Form:	
Transistor-transistor lo	gic
Input Circuit Pattern:	
14 input	
Case Outline Source	And Designator:
D-3 mil-m-38510	
Terminal Surface Tre	atment:
Solder	
Voltage Rating And T	Type Per Characteristic:
5.5 volts power source	9
Time Rating Per Cha	cteristic:
100.00 nanoseconds	propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type	e de la companya de l
Rom	
Memory Capacity:	
Unknown	
Terminal Type And Q	luantity:
24 printed circuit	
Shelf Life:	
N/a	

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Demilitarization:

Yes - demil/mli

Fiig:

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